















ESD

TVS

MOS

LDO

Diode

Sensor

DC-DC

Product Specification

Domestic Part Number	AO3414A
Overseas Part Number	AO3414A
▶ Equivalent Part Number	AO3414A

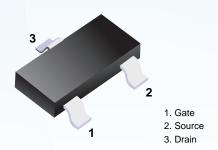




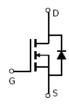
■ N-Channel Enhancement Mode

■ Features

- V_{DS} (V) = 20V
- ID = 4.2A (VGS=4.5V)
- RDS(ON) < 50m Ω (VGS = 4.5V)
- RDS(ON) < 63m Ω (VGS = 2.5V)
- RDS(ON) < 87m Ω (VGS = 1.8V)



■ Simplified outline(SOT23-3L)



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage	VDS	20	V		
Gate-Source Voltage	Vgs	±8	V		
Continuous Drain Ta=25℃	lp	4.2			
Current *1 TA=70℃	l lb	3.2	Α		
Pulsed Drain Current *2	Ідм	15			
Power Dissipation *1 T _A =25℃	- Pn	1.4	W		
Ta=70°C	FD	PD 0.9			
Themal Resistance.Junction-to-Ambient *1	RthJA	125	°C/W		
Themal Resistance.Junction-to-Case	RthJC	80	°C/W		
Junction and Storage Temperature Range	ТJ, Tsтg	-55 to 150	$^{\circ}\mathbb{C}$		

^{*1}The value of R θ JA is measured with the device mounted on 1in 2 FR-4 board with 2oz.

Copper, in a still air environment with Ta =25 $^{\circ}\mathrm{C}$

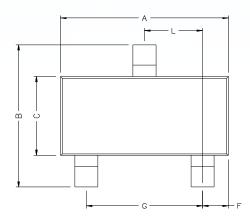


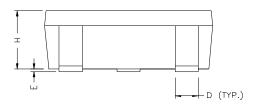
■ Electrical Characteristics Ta = 25°C

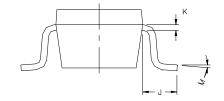
Parameter	Symbol	Testconditons	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	VDSS	ID=250μA, VGS=0V	20			V
Zana Cata Valtana Brain Commant	lana	Vps=16V, Vgs=0V			1	μ А
Zero Gate Voltage Drain Current	IDSS	Vps=16V, Vgs=0V ,TJ=55°C			5	
Gate-Body leakage current	Igss	V _{DS} =0V, V _{GS} =±8V			±100	nA
Gate Threshold Voltage	VGS(th)	Vps=Vgs lp=250µA	0.4	0.6	1	V
		Vgs=4.5V, ID=4.2A		41	50	
Chatia Dunin Causas On Banistana	Descent	Vgs=4.5V, lp=4.2A		58	70	
Static Drain-Source On-Resistance	RDS(ON)	Vgs=2.5V, ID=3.7A		52	63	m Ω
		Vgs=1.8V, ID=3.2A		67	87	Ì
On state drain current	ID(ON)	Vgs=4.5V, Vps=5V	15			А
Forward Transconductance	gFS	VDS=5V, ID=4.2A		11		S
Input Capacitance	Ciss			436		pF
Output Capacitance	Coss	Vgs=0V, Vps=-10V, f=1MHz		66		pF
Reverse Transfer Capacitance	Crss	1		44		pF
Gate resistance	Rg	Vgs=0V, Vps=0V, f=1MHz		3		Ω
Total Gate Charge	Qg			6.2		nC
Gate Source Charge	Qgs	Vgs=4.5V, Vps= =10V, lp=4.2A		1.6		nC
Gate Drain Charge	Qgd	1		0.5		nC
Turn-On DelayTime	tD(on)			5.5		ns
Turn-On Rise Time	tr	Voca 4 FV Voca 10V Dr = 2 70 Documen		6.3		ns
Turn-Off DelayTime	tD(off)	Vgs=4.5V, Vds=10V, RL=2.7 Ω ,Rgen=6 Ω		40		ns
Turn-Off FallTime	tf			12.7		ns
Body Diode Reverse Recovery Time trr		IF=4A, dı/dt=100A/ μ s		12.3		ns
Body Diode Reverse Recovery Charge	Qrr	IF=4A, dı/dt=100A/ μ s		3.5		nC
Maximum Body-Diode Continuous Current	Is				2	Α
Diode Forward Voltage	VsD	Is=1A,Vgs=0V		0.76	1	V



■ SOT23-3L







DIMENSIONS (mm are the original dimensions)

UNIT	Α	В	С	D	E	F	G	Н	K	J	L	М
mm	2.70 3.10	2.65 2.95	1.50 1.70	0.35 0.50	0 0.10	0.45 0.55	1.9	1.00 1.30	0.10 0.20	0.40	0.85 1.15	0° 10°



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